### **Pin Assignment**



# **Clock Multiplier Decoding Table 1**

#### (Multiplies Input clock by shown amount)

FBIN	S1	S0	CLK1	CLK2
CLK1	0	0	2 X ICLK	ICLK
CLK1	0	1	4 X ICLK	2 X ICLK
CLK1	1	0	ICLK	ICLK/2
CLK1	1	1	8 X ICLK	4 X ICLK
CLK2	0	0	4 X ICLK	2 X ICLK
CLK2	0	1	8 X ICLK	4 X ICLK
CLK2	1	0	2 X ICLK	ICLK
CLK2	1	1	16 X ICLK	8 XICLK

### **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description		
1	FBIN	Input	Feedback clock input.		
2	ICLK	Input	Reference clock input.		
3	GND	Power	Connect to ground.		
4	S0	Input	Select 0 for output clock per decoding table above. Pull-up.		
5	S1	Input	Select 1 for output clock per decoding table above. Pull up.		
6	CLK1	Output	Clock output per table above.		
7	VDD	Power	Connect to +3.3 V or +5.0 V.		
8	CLK2	Output	Clock output per table above. Low skew divide by two of pin 6 clock.		

### **External Components**

The MK2302-01 requires a  $0.01\mu$ F decoupling capacitor to be connected between VDD and GND. It must be connected close to the part to minimize lead inductance. No external power supply filtering is required for this device. A  $33\Omega$  series terminating resistor can be used next to each output pin.

Using CLK1 as the feedback will always result in synchronized rising edges between ICLK and CLK1. However, the CLK2 could be a falling edge compared with ICLK. IDT recommends using CLK2 feedback whenever possible. This will synchronize the rising edges of all three clocks.

#### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the MK2302-01. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	-55 to 125°C
Storage Temperature	-65 to +150° C
Junction Temperature	125°C
Power Dissipation	0.5 W

#### **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature (commercial)	0		+70	°C
Ambient Operating Temperature (industrial)	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+4.5	+5.0	+5.5	V
Power Supply Voltage (measured in respect to GND)	+3.15	+3.3	+3.45	V

### **DC Electrical Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.15		3.45	V
Operating Current	IDD			20		ma
Input High Voltage	V <sub>IH</sub>	ICLK, FBIN	2			V
Input Low Voltage	V <sub>IL</sub>	ICLK, FBIN			0.8	V
Input High Voltage	V <sub>IH</sub>	S0, S1	VDD-0.5			V
Input Low Voltage (mid-level)	V <sub>IM</sub>	S0, S1		VDD/2		V
Input Low Voltage	V <sub>IL</sub>	S0, S1			0.5	V
Output High Voltage (CMOS High)	V <sub>OH</sub>	I <sub>OH</sub> = -4 mA	VDD-0.4			V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	2.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 12 mA			0.4	V
Short Circuit Current	I <sub>OS</sub>	Each output		±70		mA
Input Capacitance	C <sub>IN</sub>	S0, S1		5		pF

**VDD = 3.3 V ±5%**, Ambient Temperature 0 to  $+70^{\circ}$  C or  $-40^{\circ}$  C to  $85^{\circ}$  C

#### VDD = 5 V ±10%, Ambient Temperature 0 to +70° C or -40° C to 85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD	5V	4.5		5.5	V
Operating Current	IDD			30		ma
Input High Voltage	V <sub>IH</sub>	ICLK, FBIN	2			V
Input Low Voltage	V <sub>IL</sub>	ICLK, FBIN			0.8	V
Input High Voltage	V <sub>IH</sub>	S0, S1	VDD-0.5			V
Input Low Voltage (mid-level)	V <sub>IM</sub>	S0, S1		VDD/2		V
Input Low Voltage	V <sub>IL</sub>	S0, S1			0.5	V
Output High Voltage (CMOS High)	V <sub>OH</sub>	I <sub>OH</sub> = -4 mA	VDD-0.4			V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	2.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 12 mA			0.4	V
Short Circuit Current	I <sub>OS</sub>	Each output		±100		mA
Input Capacitance	C <sub>IN</sub>	S0, S1		5		pF

## **AC Electrical Characteristics**

VDD = 3.3 V or 5 V ±5%, An	mbient Temperature 0 to +70° C or -40° C to 85° C
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Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency, ICLK		FBIN from CLK/2	5	See table or	n page 2	2
Output Clock Frequency		CLK1	10		168	MHz
Output to Output Skew				100	175	ps
Input to Output Jitter		40 - 150 MHz			200	ps
Input Skew		ICLK to FBIN, CLK>30 MHz, Note 1	-300		300	ps
		ICLK to FBIN, CLK<30 MHz, Note 1	-600		600	ps
Output Clock Rise Time		0.8 to 2.0 V, Note 2		0.8	1	ns
Output Clock Fall Time		2.0 to 0.8 V, Note 2		0.8	1	ns
Output Clock Duty Cycle		at VDD/2	40	49 - 51	60	%

Note 1: Assumes clocks with same rise time, measured from rising edges at VDD/2.

Note 2: Measured with  $27\Omega$  terminating resistor and 15 pF loads.

#### **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{JA}$	Still air		150		° C/W
Ambient	$\theta_{JA}$	1 m/s air flow		140		° C/W
	$\theta_{JA}$	3 m/s air flow		120		° C/W
Thermal Resistance Junction to Case	$\theta_{\text{JC}}$			40		° C/W

### Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		Inc	hes
Symbol	Min	Max	Min	Max
А	1.35	1.75	.0532	.0688
A1	0.10	0.25	.0040	.0098
В	0.33	0.51	.013	.020
С	0.19	0.25	.0075	.0098
D	4.80	5.00	.1890	.1968
E	3.80	4.00	.1497	.1574
е	1.27 E	BASIC	0.050	BASIC
Н	5.80	6.20	.2284	.2440
h	0.25	0.50	.010	.020
L	0.40	1.27	.016	.050
α	0°	<b>8</b> °	<b>0</b> °	<b>8</b> °



### **Ordering Information**

Part / Order Number	Marking	Shipping Pkg	Package	Temperature
MK2302S-01LF	230201LF	Tubes	8-pin SOIC	0 to +70° C
MK2302S-01LFT	230201LF	Tape and Reel	8-pin SOIC	0 to +70° C
MK2302S-01ILF	230201ILF	Tubes	8-pin SOIC	-40 to 85° C
MK2302S-01ILFT	2302011LF	Tape and Reel	8-pin SOIC	-40 to 85° C

#### "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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